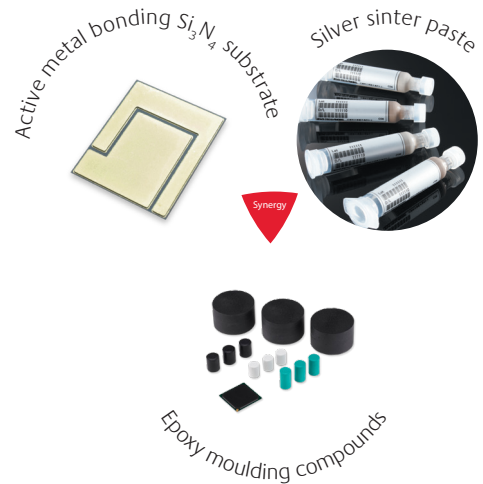


# Power Module Ceramic Substrates

## Total material solution for EV/HEV inverters

Kyocera provides advanced  $\text{Si}_3\text{N}_4$  power module substrate to innovate highly efficient automotive inverters.

### KYOCERA Synergy



### APPLICATIONS

- ▶ HEV / EV inverters
- ▶ Power switch

### FEATURES

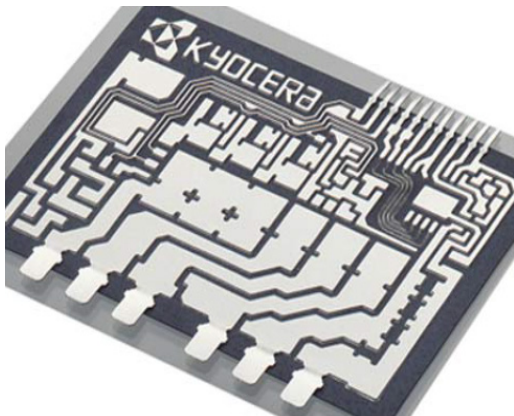
- ▶ High reliable silver plating to silver-sintering paste for SiC chip assembly
- ▶ High thermal conductivity / high flexural strength
- ▶  $\text{Si}_3\text{N}_4$  (ceramic): 85 W/mK / 820 MPa
- ▶ Copper thickness: ~ 0.8 mmt
- ▶ Fine pitch design rule: 1.0 mm gap between copper patterns

## AMB SUBSTRATE ROADMAP

### Automotive Inverters

CY		New $\text{Si}_3\text{N}_4$ 85 W/mK					
		2015	2016	2017	2018	2019	2020
Product roadmap	AMB Silicon nitride substrate	Case type (substrate size > 20 mm)					
		0.3 t Cu/0.32 t $\text{Si}_3\text{N}_4$ Au plating	0.3 t Cu/0.32 t $\text{Si}_3\text{N}_4$ Ag plating				0.5 t Cu/0.25 $\text{Si}_3\text{N}_4$ Ag plating
		Mould type (substrate size < 20 mm)					
			0.8 t Cu/0.32 t $\text{Si}_3\text{N}_4$ Ag plating				4 t Cu/0.32 t $\text{Si}_3\text{N}_4$ Ag plating
Tech. trend	Thermal conductivity	58 W	58 W/85 W				
	Insulation voltage	400 V-4 kV					
	TCT	-40 ~ 175 °C					200 °C
	Plating	NiPdAu full				NiPdAg full/selective	Electrolytic Ag selective

# AMB Ceramic Substrate for Power Module Applications

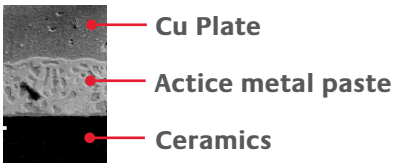


## FEATURES

- ▶ High reliability (AMB Technology)
- ▶ Variety of platings (Ni, Ni/Au, NiPdAu, Ni/Pd/Ag, Ag)
- ▶ High thermal conductivity
- ▶ Multilayer structure feasible
- ▶ Different Cu thickness plates on same substrate
- ▶ Various connector possibilities

## Reliability AMB process

- ▶ Active Metal Bonding
- ▶ Ti Compound - alloy (Ag-Cu)
- ▶ High adhesion strength to Ceramics



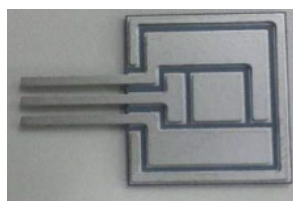
## Plating options

- ▶ Partial silver plating
- ▶ Direct silver plating
- ▶ Nickel-palladium-gold or silver plating
- ▶ Nickel-gold plating
- ▶ Nickel plating

## Connector Technologies



Lead type



Long lead type

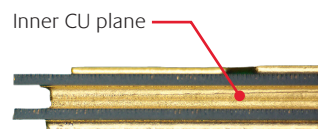


Cu PIN type



Screwable (SiN) type

## Multilayer structure



- ▶ Multilayer AMB structure
- ▶ Low inductance
- ▶ 3 dimensional routing

## Materials availability

- ▶ Si<sub>3</sub>N<sub>4</sub>: High flexural strength (85 W/mK)
- ▶ AlN: High thermal conductivity (170WmK)
- ▶ Al<sub>2</sub>O<sub>3</sub>: Low cost applications

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